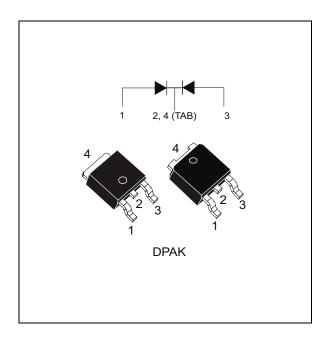




Power Schottky rectifier

Datasheet - production data



Description

High voltage dual Schottky rectifier suited to switch mode power supplies and other power converters.

Packaged in DPAK, this device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses are required.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 3 A
V_{RRM}	60 V
V _F (typ)	0.55 V

Features

- · Negligible switching losses
- Low forward voltage drop
- Low capacitance
- High reverse avalanche surge capability
- Tape and reel packing
- ECOPACK[®]2 compliant component for DPAK on demand

Characteristics STPS660CB

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode, at 25 °C unless otherwise specified)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	60	V	
I _{F(RMS)}	Forward rms current	6	Α	
I _{F(AV)}	Average forward current, $\delta = 0.5$ square wave	T _c = 115 °C	3	Α
I _{FSM}	Surge non repetitive forward current	50	Α	
T _{stg}	Storage temperature range	•	-65 to +150	°C
T _j	Maximum operating junction temperature ⁽¹⁾		125	°C

^{1.} $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal parameters

Symbol	Parameter	Max. value	Unit	
D	Junction to case per diode	Э	3.5	
R _{th(j-c)}	per device	се	2	°C/W
R _{th(c)}	coupling		0.5	

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I_ (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V _R = 60 V	-	-	30	μΑ
I IK., IVE		T _j = 125 °C		-	2.5	10	mA
V _E ⁽²⁾	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I - 2 A	-	-	0.65	V
v _F , ′	Forward voltage drop	T _j = 125 °C	I _F = 3 A	-	0.55	0.59	V

^{1.} Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.49 \times I_{F(AV)} + 0.035 \times I_{F^2(RMS)}^2$$

Table 5. Dynamic electrical characteristics (per diode)

	Symbol	Test conditions			Тур.	Max.	Unit
Ī	С	Junction capacitance	$V_R = 0 \text{ V, F} = 1 \text{ MHz, T}_j = 25 \text{ °C}$	-	815	-	pF

^{2.} Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 DPAK package information

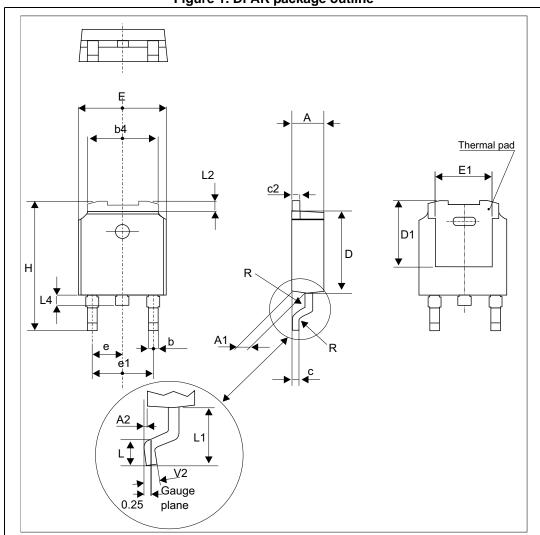


Figure 1. DPAK package outline

Note:

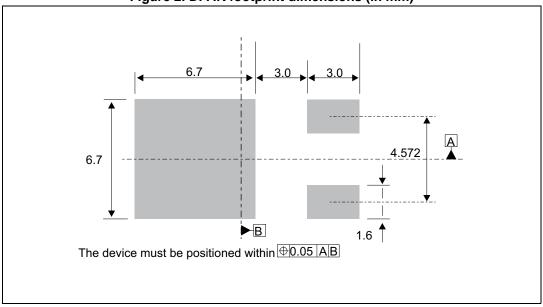
This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Package Information STPS660CB

Table 6. DPAK package mechanical data

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.18		2.40	0.085		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
b	0.64		0.90	0.025		0.035
b4	4.95		5.46	0.194		0.214
С	0.46		0.61	0.018		0.024
c2	0.46		0.60	0.018		0.023
D	5.97		6.22	0.235		0.244
D1	4.95		5.60	0.194		0.220
Е	6.35		6.73	0.250		0.264
E1	4.32		5.50	0.170		0.216
е		2.28			0.090	
e1	4.40		4.70	0.173		0.185
Н	9.35		10.40	0.368		0.409
L	1.00		1.78	0.039		0.070
L2			1.27			0.050
L4	0.60		1.02	0.023		0.040
V2	-8°		+8°	-8°		8°

Figure 2. DPAK footprint dimensions (in mm)



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS660CB-TR	S6 60C	DPAK	0.32 g	2500	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision Changes	
Jul-1998	1C	Previous version
18-Oct-2013	2	Updated package footprint graphic.
07-Jan-2015	3	Updated DPAK package information.
16-May-2017	4	Updated DPAK package information.

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